

BAT18 Silicon planar diode Rev. 02 – 31 August 2004

Product data sheet

1. Product profile

1.1 General description

Planar high performance band-switching diode in a small rectangular SOT23 SMD plastic package.

1.2 Features

- Continuous reverse voltage: max. 35 V
- Continuous forward current: max. 100 mA
- Low diode capacitance: max. 1.0 pF
- Low diode forward resistance: max. 0.7 Ω .

1.3 Applications

Band switching.

2. Pinning information

Table 1:	Pinning	
Pin	Description	Simplified outline Symbol
1	anode	
2	not connected	
3	cathode	1 + 1 + 1 + 1 + 1 + 1 + 1 + 1 + 1 + 1 +

3. Ordering information

Table 2: Orde	ering infor	mation	
Type number	Package		
	Name	Description	Version
BAT18	-	plastic surface mounted package; 3 leads	SOT23



4. Marking

Marking code [1]	
10*	

- [1] * = p: made in Hong Kong
 - * = t: made in Malaysia
 - * = W: made in China.

5. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	continuous reverse voltage		-	35	V
I _F	continuous forward current		-	100	mA
T _{stg}	storage temperature		-55	+125	°C
Tj	junction temperature		-	125	°C

6. Thermal characteristics

Table 5: Thermal characteristics

 $T_i = 25 \circ C$ unless otherwise specified.

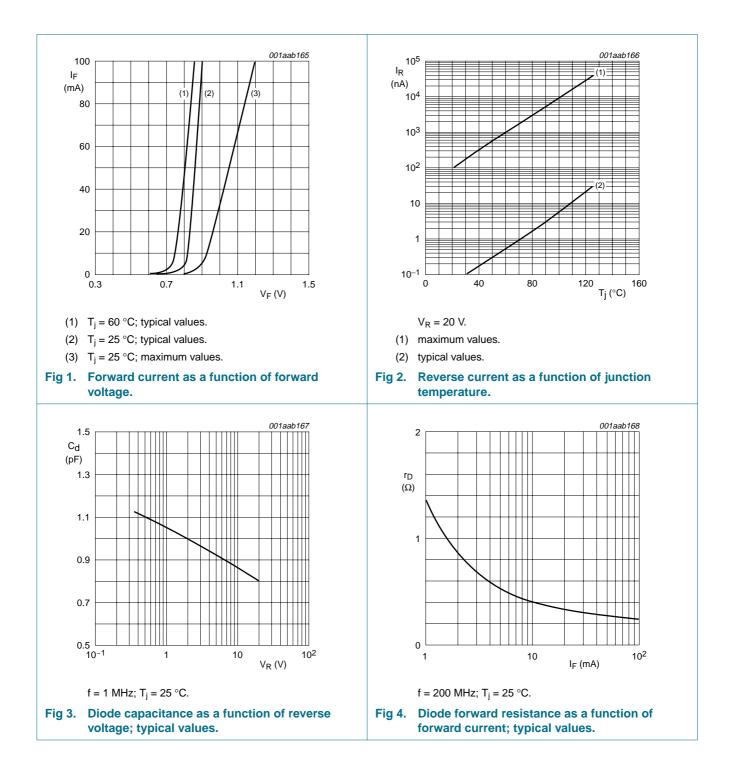
Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-tp)}	thermal resistance from junction to tie-point		330	K/W
R _{th(j-a)}	thermal resistance from junction to ambient		[<u>1]</u> 500	K/W

[1] Device mounted on a FR4 printed-circuit board.

7. Characteristics

Table 6:	Electrical characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 100 mA; see <u>Figure 1</u>	-	-	1.2	V
I _R	reverse current	see Figure 2				
		V _R = 20 V	-	-	100	nA
		$V_R = 20 \text{ V}; \text{ T}_j = 60 ^{\circ}\text{C}$	-	-	1	μA
C _d	diode capacitance	$V_R = 20 V$; f = 1 MHz; see Figure 3	-	0.8	1.0	pF
r _D	diode forward resistance	$I_F = 5 \text{ mA}; f = 200 \text{ MHz}; \text{ see } \frac{\text{Figure 4}}{1000 \text{ MHz}}$	-	0.5	0.7	Ω

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8. Package outline

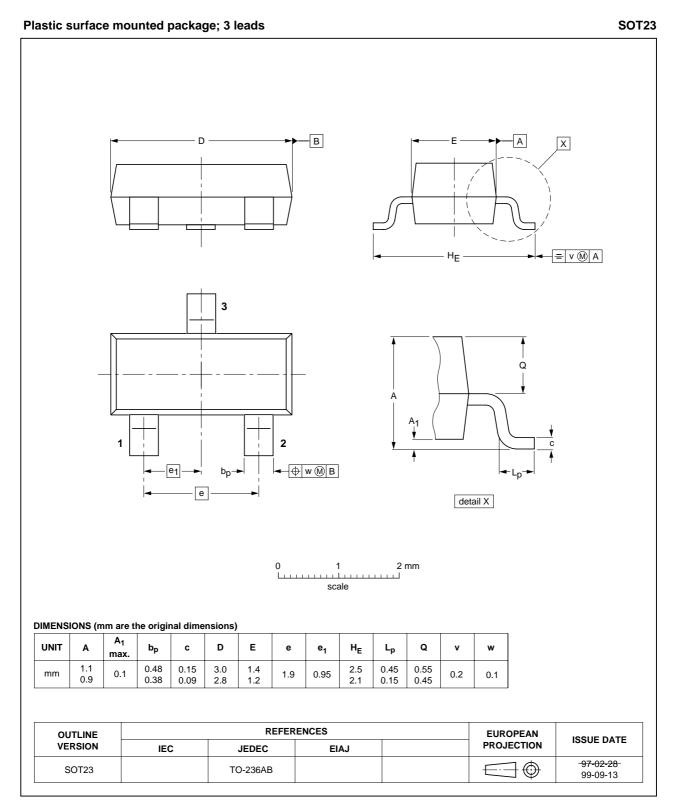


Fig 5. Package outline.

9397 750 13385 Product data sheet

9. Revision history

Table 7: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BAT18_2	20040831	Product data sheet	-	9397 750 13385	BAT18_1
Modifications:	odifications: • The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.			v presentation and	
	• <u>Table 3</u> : n	narking code changed.			
BAT18_1	19960313	Product specification	-	not applicable	-

10. Data sheet status

Level	Data sheet status [1]	Product status ^[2] ^[3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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111	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

11. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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14. Contents

1	Product profile 1
1.1	General description
1.2	Features
1.3	Applications 1
2	Pinning information 1
3	Ordering information 1
4	Marking 2
5	Limiting values 2
6	Thermal characteristics 2
7	Characteristics 2
8	Package outline 4
9	Revision history 5
10	Data sheet status 6
11	Definitions 6
12	Disclaimers 6
13	Contact information6



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